

COMPOSITION DEPENDENCE OF SOFT MODE IN $Pb_xSr_{1-x}TiO_3$ ferro-Electric MIXED CRYSTALS

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ABSTRACT

The composition dependence of soft mode in $Pb_xSr_{1-x}TiO_3$ (PST) single crystals has been theoretical investigated in para-electric phase for various compositions. Using model Hamiltonian [For pure anharmonic crystal in presence of defect (impurity)] and Green's functions technique. Soft mode is estimated for various values of x. As x increases value of soft mode frequency decreases at constant temperature and as T increases the value of soft mode frequency increases at constant x.

Keywords: Model Hamiltonian, Green's Functions Technique, Soft Mode Frequency, Anharmonic Crystal, Single Crystal.

Introduction

Solid solutions of lead strontium titanate (PST) are very interesting ferro-electric materials which gain considerable attention due to useful in broad range of electric devices such as pyro-electric detector, DRAM capacitors, tunable microwave devices etc. PST is the most promising material because it is good insulator with large value of relative dielectric constant and low value of dielectric loss near ambient temperature.

It is easy to control the dielectric properties of the PST by adjusting [Pb/Sr] ratio. Pure $SrTiO_3$ is intrinsic quantum para-electric. It is known that permittivity peaks can be induced in $SrTiO_3$ by introducing substitutional impurities into the lattice¹. In the present paper, $Pb_xSr_{1-x}TiO_3$ with Pb contents x varies from 0 to 1.0. $(Pb, Sr)TiO_3$ solid solutions belong to ferro-electric materials of the form $(A'A'')BO_3$ type. Both constituents of this solution are ferro-electric.

This work is aimed at the determination of an influence of the ferro-electric components PT and ST on physical properties like. Softmode of PST as well as a character.

Perovskites are known to exhibit a lot of useful properties². They possess high dielectric coefficients over a wide temperature and frequency range. They are used as dielectrics in integrated or surface mounted device capacitors. The remarkable piezo-electric effect is applied in a variety of electromechanical sensors, actuators and transducers. Infrared sensors need a high pyro-electric coefficient which is available with this class of materials³. Tunable thermistor properties in semiconducting ferro-electrics are used in positive temperature co-efficient resistors (PTCR)⁴.

Lead Strontium titanate $Pb_xSr_{1-x}TiO_3$ (PST) which is known to adopt ABO_3 type solution, is a continuous solid solution of $PbTiO_3$ (PTO) and $SrTiO_3$ (STO) over the whole concentration range. The properties of $Pb_xSr_{1-x}TiO_3$ are known to depend on the composition x ^{5,6,7}. $SrTiO_3$ is usually added to $PbTiO_3$ as a shifter in order to move the Curie-point T_C to lower temperatures. It is well established that T_C of $PbTiO_3$ decreases linearly with the amount of Sr in place of Pb. For bulk $Pb_xSr_{1-x}TiO_3$, the Curie-point varies from $-236^\circ C$ to $490^\circ C$ whereas the dielectric constant (measured at room temperature and frequency of 1KHz) increases from $\epsilon \sim 300$ to $\epsilon \sim 1100$ for x from x=0.0 to x=1.0^{8,9,10,11}.

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In the present paper, an expression for the soft mode frequency in $Pb_xSr_{1-x}TiO_3$ ferro-electric crystals has been derived by designing a model Hamiltonian for anharmonic ferro-electric crystal and then modified by adding a defect (impurity) term for $Pb_xSr_{1-x}TiO_3$. The mass and force constant changes are taken into account. The variation of soft mode frequency with temperature and impurity concentration x (of Pb) in pure $SrTiO_3$ crystal has been theoretically studied using Green's function technique.

Theory

Hamiltonian and Green's Function

The Hamiltonian which includes the anharmonicity upto fourth -order in the potential energy due to interaction of soft mode coordinates, resonant interaction and scattering terms are considered. The impurities introduced are characterized by different mass than the host atoms and with modified nearest neighbour harmonic force constants around their sites. The influence on the anharmonic coupling coefficients in the Hamiltonian, being small is neglected. The modified Hamiltonian of a mixed perovskite, in para-electric phase which includes defects (substitutional impurity) is used in present study and is exactly similar as used earlier¹² is given

$$H' = H + H_D \dots \dots \dots (1)$$

where H is Hamiltonian for pure crystal and H_D is the contribution by the defect in Hamiltonian which involves the effect of mass change and harmonic force constant change between the impurity and host lattice atoms due to substitutional defects.

Where

$$\begin{aligned} H = & \sum_k \frac{\hbar \omega_k^a}{4} (A_k^{a+} A_k^a + B_k^{a+} B_k^a) + \sum_k' \frac{\hbar \omega_k^0}{4} (A_k^{0+} A_k^0 + B_k^{0+} B_k^0) - \\ & \frac{\hbar \omega_0^0}{4} (A_0^{0+} A_0^0 + B_0^0 B_0^0) + \sum_k \hbar F(k) A_0^0 A_k^{0+} A_k^a + \sum_k \hbar \beta^a(k) A_0^{02} A_k^{0+} A_k^0 + \\ & \sum_k \hbar \beta^0(k) A_0^{02} A_k^{a+} A_k^a + \sum_{k_1 k_2 k_3} \hbar \varphi(k_1 k_2 k_3) A_0^0 A_{k_1}^0 A_{k_2}^a A_{k_3}^a + \\ & \sum_{k_1 k_2 k_3} \hbar \psi(k_1 k_2 k_3) A_0^0 A_{k_1}^0 A_{k_2}^0 A_{k_3}^0 + \hbar V A_0^{04} + \\ & \hbar E \\ & \{-\alpha A_0^0 + \\ & \sum_k A(k) A_k^a A_k^{0+} + \sum_{k,\lambda} B^\lambda(k) A_0^0 A_k^{\lambda+} A_k^\lambda + \sum_{k_1 k_2 k_3} C(k_1, k_2, k_3) A_{k_1}^0 A_{k_2}^a A_{k_3}^a + \\ & \sum_{k_1 k_2 k_3} D_1(k_1, k_2, k_3) A_{k_1}^0 A_{k_2}^0 A_{k_3}^0 - D_1(0,0,0) A_0^{03}\} \\ = & H_1 + H_2 + H_0 + H_3 + \dots \dots \dots H_{14}, \dots \dots \dots (2) \end{aligned}$$

Where

$$F(k) = \frac{P(k)}{\sqrt{N}} \cdot \frac{1}{(\omega_k^0 \omega_k^a)^{\frac{1}{2}}} \dots \dots \dots (2a)$$

$$\beta^a(k) = \frac{G^a(k)}{N} \cdot \frac{1}{\omega_k^0} \dots \dots \dots (2b)$$

$$\beta^0(k) = \frac{G^0(k)}{N} \cdot \frac{1}{\omega_k^a} \dots \dots \dots (2c)$$

$$\varphi(k_1, k_2, k_3) = \frac{1}{\sqrt{N}} \gamma(k_1, k_2, k_3) \frac{\hbar^{\frac{1}{2}}}{(\omega_{k_1}^0 \omega_{k_2}^a \omega_{k_3}^a)^{\frac{1}{2}}} \dots \dots \dots (2d)$$

$$\psi(k_1, k_2, k_3) = \frac{1}{\sqrt{N}} \mu(k_1, k_2, k_3) \frac{\hbar^{\frac{1}{2}}}{(\omega_{k_1}^0 \omega_{k_2}^0 \omega_{k_3}^0)^{\frac{1}{2}}} \dots \dots \dots (2e)$$

$$A(k) = \frac{A'(k)}{(\omega_k^0 \omega_k^a)^{\frac{1}{2}}} \dots \dots \dots (2f)$$

$$B^\lambda(k) = \frac{B'^\lambda(K)}{\sqrt{N}} \cdot \frac{1}{\omega_k^\lambda} \dots\dots\dots(2g)$$

$$C(k_1, k_2, k_3) = C'(k_1, k_2, k_3) \frac{\hbar^{\frac{1}{2}}}{(\omega_{k_1}^0 \omega_{k_2}^a \omega_{k_3}^a)^{\frac{1}{2}}} \dots\dots\dots(2h)$$

$$D(k_1, k_2, k_3) = D'(k_1, k_2, k_3) \frac{\hbar^{\frac{1}{2}}}{(\omega_{k_1}^0 \omega_{k_2}^0 \omega_{k_3}^0)^{\frac{1}{2}}} \dots\dots\dots(2i)$$

$$V = \Psi(0, 0, 0) \dots\dots\dots(2j)$$

$$D_1' = D_1(0, 0, 0) \dots\dots\dots(2k)$$

In the above equations $G^0(k)$ and $G^a(K)$ are the Fourier transforms of 3rd order anharmonic force constants, $Y(K_1, K_2, K_3)$ and $\mu(K_1, K_2, K_3)$ are the Fourier transformed 4th order anharmonic force constants. (α) ; $A(K)$, $B^\lambda(K)$ and $C'(K_1, K_2, K_3)$, $D'(K_1, K_2, K_3)$ represent the linear, second and third-order electric moment co-efficients respectively. The primed sum in H_2 is taken for $k \neq 0$.

H_D is the contribution by the defect in Hamiltonian which involves the effect of mass change and harmonic force constant change between the impurity and host lattice atoms due to substitutional defects and is given by¹³

$$H_D = -\hbar C(0,0) B_0^0 B_0^0 + \hbar D(0,0) A_0^0 A_0^0 - \hbar B_0^0 X + \hbar A_0^0 Y + \hbar Z, \dots\dots\dots(3)$$

With

$$X = \sum_{k,\lambda} C(k^\lambda, 0) B_k^\lambda \dots\dots\dots(3a)$$

$$Y = \sum_{k,\lambda} D(k^\lambda, 0) A_k^\lambda \dots\dots\dots(3b)$$

And

$$Z = \sum_{k_1, k_2, \lambda} [D(k_1^\lambda, k_2^\lambda) A_{k_1}^\lambda A_{k_2}^\lambda - C(k_1^\lambda, k_2^\lambda) B_{k_1}^\lambda B_{k_2}^\lambda] + \sum_{k_1, k_2} [D(k_1^a, k_2^0) A_{k_1}^a A_{k_2}^0 - C(k_1^a, k_2^0) B_{k_1}^a B_{k_2}^0] \dots\dots\dots(3c)$$

Here $\lambda = a, 0$ are for acoustic and optic modes respectively. The defect parameters $C(k_1, k_2)$ and $D(k_1, k_2)$ depend upon the changes in the mass and force constants due to the substitutional defects respectively and are given by

$$C(k_1, k_2) = \frac{1}{2\mu} (M_0/2N) (\omega_{k_1} \omega_{k_2})^{\frac{1}{2}} e(k_1) e(k_2) \times \{\sum_{\ell}^n f \exp. [i(k_1 + k_2) \cdot R(\ell)] - \sum_{\ell}^n \exp. [i(k_1 + k_2) \cdot R(\ell)]\} \dots\dots\dots(3d)$$

and

$$D(k_1, k_2) = \frac{1}{4N} (\omega_{k_1} \omega_{k_2})^{-\frac{1}{2}} \times \sum_{\ell\alpha\ell'\beta} [\Delta\phi_{\alpha\beta}(\ell\ell')/M_0] \times e(k_1) e(k_2) \times \exp. [i\{k_1 \cdot R(\ell) + k_2 \cdot R(\ell')\}], \dots\dots\dots(3e)$$

where $e(k)$ is the polarization vector, $R(\ell)$ the equilibrium position vector of the ℓ -th atom,

$C(k_1, K_2)$ vanishes when n is either zero or N . $\Delta\phi$ denotes the force constant change, ℓ and ℓ' refer to the impurity and its nearest neighbours and $\mu = [M M'/(M'-M)]$. M_0 is the weighted harmonic mean of the masses of all atoms and is defined by the relation

$$\frac{1}{M_0} = \frac{f}{M'} + \frac{1-f}{M} \dots\dots\dots(3f)$$

with $f = \frac{n}{N}$. Here N is the total number of atoms in the crystal whose (N-n) lattice sites are occupied by atoms of mass M while n sites are occupied by randomly distributed substitutional impurities each of mass M' .

In order to get the effect of defect on soft mode frequency, we transform the Hamiltonian H' as given by Naithaniet. al¹³. The transformed Hamiltonian is obtained as

$$H_T = H + H_D + \hbar \omega_0^0 g A_0^0 \dots\dots\dots(4)$$

Where $g = \frac{\alpha}{\omega_0^0}$.

The retarded Green's function $G_0^0(t-t')$ for optic phonon is defined as

$$G_0^0(t-t') = \langle\langle A(t); A(t') \rangle\rangle_{\omega+i\varepsilon} \quad \text{or} \quad G_0^0(\omega+i\varepsilon) = G'(\omega) - iG''(\omega)$$

(6) The real (ε') and imaginary parts ($\tan \delta$) of dielectric constant are related to Green's function as

$$\varepsilon'(\omega) - 1 = -8 \pi^2 N \mu^2 G'(\omega) \quad (7) \quad \text{and} \quad \tan \delta = G''(\omega) / G'(\omega)$$

(8)

The equation of motion for Green's function is

$$i\hbar \frac{d}{dt} G(t, t') = \hbar \frac{d}{dt} \theta(t-t') \langle [A(t), B(t')] \rangle$$

+ $\langle\langle [A(t), H_T]; B(t') \rangle\rangle$ (9) Using this equation of motion, modified Hamiltonian, Fourier transforming and shaping in Dyson's equation form, we get

$$G_0^0(\omega+i\varepsilon) = \frac{\omega_0^0}{\pi[\omega^2 - v^2(\omega) + i\Gamma_0^0(\omega)]} \quad (10)$$

Here $v^2(\omega) = v_0^2(\omega) + \Delta(v_D^2(\omega))$ (10a) where

$$v_0^2(\omega) = -(\omega_0^0)^2 + 4\omega_0^0 \bar{Q} + \Delta_0(\omega) \quad (10b)$$

and

$$\Delta(v_D^2(\omega)) = 4\omega_0^0 D(0,0) + 4\omega_0^0 \sum_{k,\lambda} D^2(k,\lambda,0) [\tilde{\omega}_k^\lambda / \omega^2 - (\tilde{\omega}_k^\lambda)^2] - 4(\omega^2 / \omega_0^0) \sum_{k,\lambda} C^2(k,\lambda,0) [\tilde{\omega}_k^\lambda / \omega^2 - (\tilde{\omega}_k^\lambda)^2] + 4\omega \sum_{k,\lambda} C(k,\lambda,0) D^*(k,\lambda,0) \times [\tilde{\omega}_k^\lambda / \omega^2 - (\tilde{\omega}_k^\lambda)^2] - 4\omega \sum_{k,\lambda} C^*(k,\lambda,0) D(k,\lambda,0) [\tilde{\omega}_k^\lambda / \omega^2 - (\tilde{\omega}_k^\lambda)^2] + 96V^2 \times \omega_0^0 [(1+3(N_0^0)^2) * 3\Omega / \omega^2 - (3\Omega)^2 - [1 - ((N_0^0)^2)] * \Omega / \omega^2 - (3\Omega)^2] \dots (10c)$$

The notations used here are in the same sense as used by Yadav et al¹² and Naithani et al¹³.

Temperature dependence of $v^2(\omega)$ can be written as

$$v^2(\omega) = -(\omega_0^0)^2 + \gamma_1 T + \gamma_2 T^2 + \Delta(v_D^2) \quad \dots(11)$$

where $\Delta_0(\omega)$ (shift in phonon frequency corresponds to pure crystal, $\Delta(v_D^2(\omega))$ is temperature independent part due to defect and γ_1 and γ_2 are temperature dependent parts in $v^2(\omega)$ and depend on anharmonic force- constant and electric dipole moment terms.

Thus from equation (11), we conclude

$$\frac{v^2(\omega)}{\gamma_1} = -\frac{(\omega_0^0)^2}{\gamma_1} + \frac{\gamma_1 T}{\gamma_1} + \frac{\Delta(v_D^2(\omega))}{\gamma_1} + \frac{\gamma_2 T^2}{\gamma_1}$$

$$\frac{v^2(\omega)}{\gamma_1} = (T - T_c' + \xi T^2) \dots (11a)$$

Where $T_c' = -\frac{(\omega_0^0)^2}{\gamma_1} + \frac{\Delta(v_D^2(\omega))}{\gamma_1}$ and $\xi = \frac{\gamma_2}{\gamma_1}$ (non linearity constant).

Equation (11a) can be reduced now as

$$v^2(\omega) = \gamma_1 (T - T_c' + \xi T^2) \quad \dots\dots\dots(12)$$

or $v^2(\omega) = \gamma_1 (T - T_c')$ and $\xi = -1.49 \times 10^{-3} \text{ cm}^{-1} \text{ k}^{-2}$ is negligible for ST¹⁴. (13)

Here $T_c' = T_c + \Delta(T_c)$ is the new Curie-temperature in presence of defect impurity.

Here, $\Delta(T_c) = -\frac{\Delta(v_D^2(\omega))}{\gamma_1} \quad \dots\dots\dots (13a)$

Thus T_c is one of the parameters which is very sensitive to impurity (x). The above results show that T_c varies linearly with x.

Equation 13 shows that the change in Curie temperature depends on substitutional impurity.

$\Delta(v_D^2(\omega))$ (temperature independent part due to defect) and γ_1 (anharmonic coupling constant) and hence ΔT_c is a function of mass change due to defect and anharmonic constants.

- **Composition dependence of soft mode frequency**

Using relation $\nu = \gamma_1^{\frac{1}{2}}(T - T_c')^{\frac{1}{2}}$ as stated above (taking $\gamma_1^{\frac{1}{2}} = 1.548 \times 10^{11}$ Hz from G. Shirane et al.¹⁴ and T_c from the reference^{11,15}), soft mode frequency ν for $\text{Pb}_x\text{Sr}_{1-x}\text{TiO}_3$ crystals are calculated for various values of x at 800K. The values are given in table 1. The variation of soft mode frequency versus impurity parameter x in $\text{Pb}_x\text{Sr}_{1-x}\text{TiO}_3$ have been shown in figure 1.

Table 1: Soft mode frequency versus composition at T=800K.

X	T_c (K)	$\nu = \gamma_1^{\frac{1}{2}}(T - T_c')^{\frac{1}{2}}$ ($\times 10^{12}$ Hz)
0	37	4.276
0.1	109.6	4.067
0.2	182.2	3.848
0.3	254.8	3.615
0.4	327	3.367
0.5	400	3.096
0.6	472.6	2.801
0.7	545.2	2.471
0.8	617.1	2.094
0.9	690.4	1.621
1.0	763	0.942

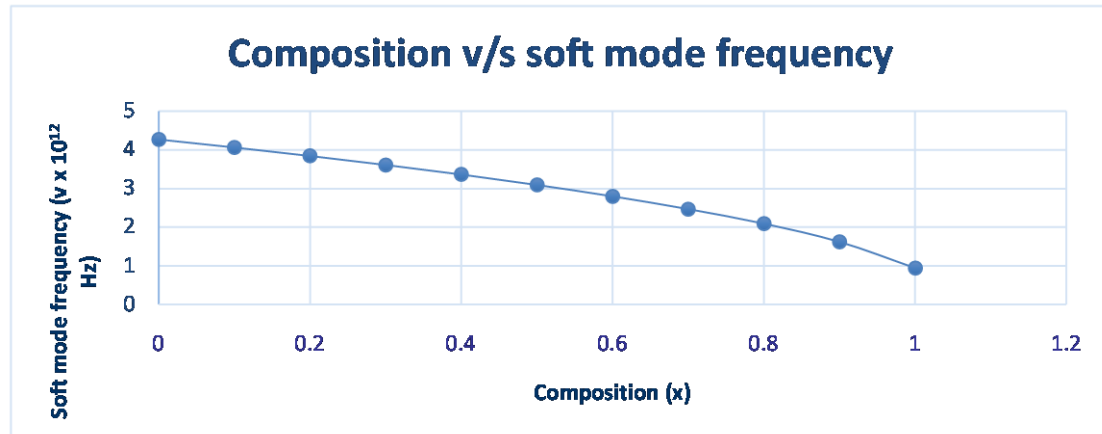


Fig. 1: Variation of soft mode frequency with composition x in $\text{Pb}_x\text{Sr}_{1-x}\text{TiO}_3$

- **Soft mode frequency as a function of temperature**

For different value of x, ν is calculated as a function of temperature using the relation $\nu = \gamma_1^{\frac{1}{2}}(T - T_c')^{\frac{1}{2}}$. The various calculated values are given in table 2(a) to 2(k) and are shown in figure 2.

Table 2(a): Soft mode ν /s temperature of SrTiO_3 , $T_c = 37\text{K}$, $x=0$

T(K)	50	60	70	80	90	100	300	400
$\nu \times 10^{11}$ Hz	5.58	7.42	8.89	10.15	11.27	12.29	25.10	29.49

Table 2(b): Soft mode ν /s temperature of $\text{Pb}_{0.1}\text{Sr}_{0.9}\text{TiO}_3$, $T_c = 109.6\text{K}$, $x=0.1$

T(K)	110	120	130	140	150	200	300	400
$\nu \times 10^{11}$ Hz	0.98	4.99	6.99	8.54	9.84	14.72	21.36	26.38

Table 2(c): Soft mode v/s temperature of $\text{Pb}_{0.2}\text{Sr}_{0.8}\text{TiO}_3$, $T_C = 182.2\text{K}$, $x=0.2$

T(K)	190	200	210	220	230	300	400	500
$\nu \times 10^{11}\text{Hz}$	4.32	6.53	8.16	9.52	10.70	16.80	22.85	27.60

Table 2(d): Soft mode v/s temperature of $\text{Pb}_{0.3}\text{Sr}_{0.7}\text{TiO}_3$, $T_C = 254.8\text{K}$, $x=0.3$

T(K)	260	270	280	290	300	400	500	600
$\nu \times 10^{11}\text{Hz}$	3.53	6.04	7.77	9.18	10.41	18.65	24.24	28.76

Table 2(e): Soft mode v/s temperature of $\text{Pb}_{0.4}\text{Sr}_{0.6}\text{TiO}_3$, $T_C = 327\text{K}$, $x=0.4$

T(K)	330	340	350	360	370	400	500	600
$\nu \times 10^{11}\text{Hz}$	2.68	5.58	7.42	8.89	10.15	13.23	20.36	25.58

Table 2(f): Soft mode v/s temperature of $\text{Pb}_{0.5}\text{Sr}_{0.5}\text{TiO}_3$, $T_C = 400\text{K}$, $x=0.5$

T(K)	410	420	430	440	450	500	600	700
$\nu \times 10^{11}\text{Hz}$	4.90	6.92	8.48	9.79	10.95	15.48	21.89	26.81

Table 2(g): Soft mode v/s temperature of $\text{Pb}_{0.6}\text{Sr}_{0.4}\text{TiO}_3$, $T_C = 472.6\text{K}$, $x=0.6$

T(K)	480	490	500	510	520	600	700	800
$\nu \times 10^{11}\text{Hz}$	4.21	6.46	8.10	9.47	10.66	17.47	23.34	28.01

Table 2(h): Soft mode v/s temperature of $\text{Pb}_{0.7}\text{Sr}_{0.3}\text{TiO}_3$, $T_C = 545.2\text{K}$, $x=0.7$

T(K)	550	560	570	580	590	600	700	800
$\nu \times 10^{11}\text{Hz}$	3.39	5.96	7.71	9.13	10.36	11.46	19.26	24.71

Table 2(i): Soft mode v/s temperature of $\text{Pb}_{0.8}\text{Sr}_{0.2}\text{TiO}_3$, $T_C = 617.1\text{K}$, $x=0.8$

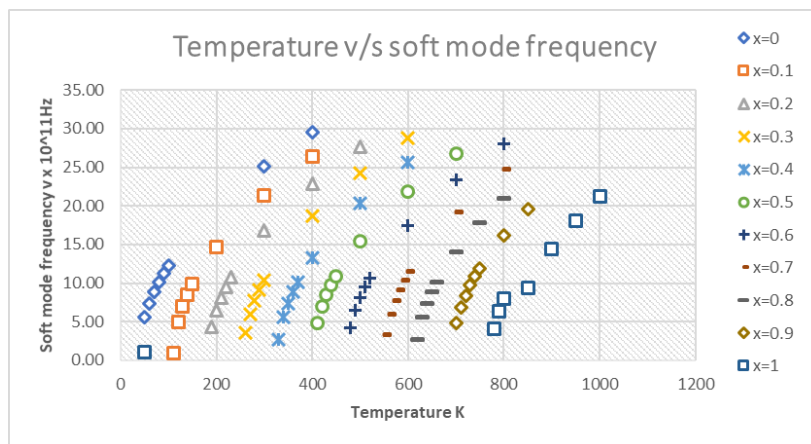
T(K)	620	630	640	650	660	700	750	800
$\nu \times 10^{11}\text{Hz}$	2.64	5.56	7.41	8.88	10.14	14.09	17.85	20.94

Table 2(j): Soft mode v/s temperature of $\text{Pb}_{0.9}\text{Sr}_{0.1}\text{TiO}_3$, $T_C = 690.4\text{K}$, $x=0.9$

T(K)	700	710	720	730	740	750	800	850
$\nu \times 10^{11}\text{Hz}$	4.80	6.85	8.42	9.74	10.90	11.95	16.21	19.56

Table 2(k): Soft mode v/s temperature of PbTiO_3 , $T_C = 763\text{K}$, $x=1.0$

T(K)	770	780	790	800	850	900	950	1000
$\nu \times 10^{11}\text{Hz}$	4.10	6.38	8.04	9.42	14.44	18.12	21.17	23.83

**Fig. 2: Variation of soft mode frequency with Temperature in $\text{Pb}_x\text{Sr}_{1-x}\text{TiO}_3$**

Discussion

In the present study, we have calculated the soft mode frequency and its temperature and composition dependence in a doped displacive anharmonic crystal using Green's function technique. Both the mass and force constant change due to substitutional impurity have been taken into account in the crystal Hamiltonian augmented with the higher order anharmonic terms. The softmode which has an imaginary frequency in harmonic approximation is renormalized and the lowest order anharmonic interaction that can stabilize the mode, is the fourth order. The soft mode frequency is impurity dependent (indirectly T_c) and depends upon the relative magnitudes and sign of the defect parameters C and D. The present study deals with the variation of the soft mode with an increasing component of Pb and temperature both in an anharmonic displaciveferro-electrics. It is clear that soft mode frequency is stabilized in presence of impurity and higher-order anharmonicity. If anharmonicity and impurity effects are neglected, soft mode frequency is imaginary due to cancellation effects of competing forces. From section 2, it is clear that soft mode frequency increases with increasing impurity contents and increasing temperature in the said range of the temperature. In the high temperature paraelectric phase, the soft mode frequency (equation 12) can be rationalized as

$$\nu^2 = A_1 + A_2 T + A_3 T^2,$$

where A_1 , A_2 and A_3 are temperature independent co-efficients and in the vicinity of Curie temperature, softmode is approximated (neglecting A_3 being very-very small) as

$$\nu = K(T - T_c')^{\frac{1}{2}}; \quad T_c' = -\frac{A_1}{A_2}; \quad K = A_2^{\frac{1}{2}}.$$

From the text, it is also clear that impurity changes Curie-temperature (T_c).

The quantitative dependence of the soft mode frequency discussed here agrees with the previous experimental and theoretical values¹⁶. The treatment adopted here leads one to see the comparative variation of the softmode frequency with variation of defects and temperature in presence of anharmonicity. From figure 1, it is clear that softmode frequency varies with the variation of Pb content concentration on the pure Strontium titanate crystal. The soft mode frequency has the highest value for a pure Strontium titanate crystal and continuously decreases when impurity of lead increases. The soft mode frequency shows a sharp decrease at $x=0.6$, which is due to large value of defect parameter and has the lowest values for $x= 1.0$ in the calculated one. Figure 2, indicates that softmode variations with temperature are of similar trends for all compositions.

References

1. Chen. Ang, Yu z.; Scott, J. ;Loidle, A. ; Gou, R. and Bhall, A. S.-J. Phys. Chem. Solids, 61, 191 (2000).
2. Xu, Y.- "Ferro-electric materials and their application", North Holland, New York, (1991)
3. Liu, S.; Liu, M.; Zeng, Y. and Huong, Y.-Mater. Sci. Eng. B, 20, 149 (2002)
4. Bomlai, P.; Sirikulrat, N. and Tunakasiri, T.-Mater. Lett., 59, 118 (2005).
5. Peng-ZuGe , Xiao-Dong Jian , Xiong-Wei Lin , Xin-Gui Tang , * , Zhi Zhu , Qiu-Xiang Liu , Yan-Ping Jiang , Tian-Fu Zhang , Sheng-Guo Lu , - Journal of Materiomics 5 (2019) 118-126
6. M. Jain, P. Bhattacharya, Yu.I. Yuzyuk, R.S. Katiyar, and A.S. Bhalla,-Mat. Res. Soc. Symp. Proc. Vol. 784 (2004).
7. M. Tarnaoui, N. Zaim, M. Kerouad, A. Zaim,-Computational Materials Science 183 (2020) 109816
8. Wodecka, B. D.; Lisinska, A. C. and Orkisz, T.-Mater. Sci., Polland, 25,791 (2007).
9. Vijendra A. Chaudhari and Govind K. Bichile,-Hindawi Publishing Corporation Smart Materials Research Volume 2013
10. F. M. Pontes, E. J. H. Lee, E. R. Leite, E. Longo, -Journal of Materials Science **35** (2000) 4783 – 4787
11. Ying Chen, Genshui Wang, Junyu Zhu, XiaodongTang,-Applied Physics Letters · February 2011
12. Yadav, M. S.; Singh, Parminder; Kumar, S. and Deorani, S. C. –J. of Pure and Applied Physics, 22, 2 (2010)
13. Naithani, U. C. and Baluni, G. N. –Indian Journal of Pure and Applied Physics, 24, 446 (1986).
14. Shirane, G. and Yamada, Y.-J. Phys. Soc., Jpn. 26, 396 (1969).
15. Sunil Kumar ,M. S. Yadav,Neetu Sharma and S. C.Deorani,-"Curie-Temperature Variation in Pervoskite SrTiO₃ Containing Pb as Substitutional Impurities (In Press).

